

Low $V_{CE(sat)}$ Transistor (Strobe flash)

($-20V$, $-10A$)

2SA1834

●Features

- 1) Low saturation voltage, typically $V_{CE(sat)} = -0.16V$ at $I_C / I_B = -4A / -50mA$.
- 2) High current capacity, typically $I_C = -10A$ for DC operation and $-15A$ for 10ms pulse.
- 3) Complements the 2SC5001.

●Packaging specifications and hfe

Type	2SA1834
Package	CPT3
hFE	RS
Code	TL
Basic ordering unit (pieces)	2500

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	-30	V
Collector-emitter voltage	V_{CEO}	-20	V
Emitter-base voltage	V_{EB0}	-6	V
Collector current	I_C	-10	A
	I_{CP}	-15	A *
Base current	I_B	-2	A
Collector power dissipation	P_C	1	W
		10	W (Tc=25°C)
Junction temperature	T_J	150	°C
Storage temperature	T_{stg}	-55~+150	°C

* Single pulse $P_w=10ms$

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	-30	—	—	V	$I_C = -50 \mu A$
Collector-emitter breakdown voltage	BV_{CEO}	-20	—	—	V	$I_C = -1mA$
Emitter-base breakdown voltage	BV_{EB0}	-6	—	—	V	$I_E = -50 \mu A$
Collector cutoff current	I_{CBO}	—	—	-1	μA	$V_{CB} = -20V$
Emitter cutoff current	I_{EBO}	—	—	-1	μA	$V_{EB} = -5V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	-0.16	-0.25	V	$I_C/I_B = -4A/-0.05A$ *
Base-emitter saturation voltage	$V_{BE(sat)}$	—	-0.9	-1.2	V	$I_C/I_B = -4A/-0.05A$ *
DC current transfer ratio	hFE1	120	—	560	—	$V_{CE} = -2V$, $I_C = -0.5A$ *
	hFE2	82	—	—	—	$V_{CE} = -2V$, $I_C = -4A$ *
Transition frequency	f_T	—	150	—	MHz	$V_{CE} = -5V$, $I_E = 1.5A$, $f = 50MHz$
Output capacitance	C_{ob}	—	220	—	pF	$V_{CB} = -10V$, $I_E = 0A$, $f = 1MHz$

* Measured using pulse current.

(96-106-B217)

Low $V_{CE(sat)}$ Transistor (Strobe flash)

(20V, 10A)

2SC5001

●Features

- 1) Low saturation voltage, typically $V_{CE(sat)} = 0.13V$ at $I_C / I_B = 4A / 50mA$.
- 2) High current capacity, typically $I_C = 10A$ for DC operation 15A for 10ms pulse.
- 3) Complements the 2SA1834.

●Packaging specifications and hfe

Type	2SC5001
Package	CPT3
hFE	QR
Code	TL
Basic ordering unit (pieces)	2500

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	30	V
Collector-emitter voltage	V_{CEO}	20	V
Emitter-base voltage	V_{EB0}	6	V
Collector current	I_C	10	A
	I_{CP}	15	A *
Base current	I_B	2	A
Collector power dissipation	P_C	1	W
		10	W (Tc=25°C)
Junction temperature	T_J	150	°C
Storage temperature	T_{stg}	-55~+150	°C

* Single pulse $P_w=10ms$

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	30	—	—	V	$I_C = 50 \mu A$
Collector-emitter breakdown voltage	BV_{CEO}	20	—	—	V	$I_C = 1mA$
Emitter-base breakdown voltage	BV_{EB0}	6	—	—	V	$I_E = 50 \mu A$
Collector cutoff current	I_{CBO}	—	—	1	μA	$V_{CB} = 20V$
Emitter cutoff current	I_{EBO}	—	—	1	μA	$V_{EB} = 5V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	0.13	0.25	V	$I_C/I_B = 4A/0.05A$
Base-emitter saturation voltage	$V_{BE(sat)}$	—	—	1.2	V	$I_C/I_B = 4A/0.05A$
DC current transfer ratio	hFE1	120	—	390	—	$V_{CE}/I_C = 5V/0.1A$
DC current transfer ratio	hFE2	82	—	—	—	$V_{CE} = 2V$, $I_C = 4A$
Transition frequency	f_T	—	150	—	MHz	$V_{CE} = 5V$, $I_E = -1.5A$, $f = 50MHz$
Output capacitance	C_{ob}	—	220	—	pF	$V_{CB} = 10V$, $I_E = 0A$, $f = 1MHz$

(96-193-D217)